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# PJQ4402P

#### 30V N-Channel Enhancement Mode MOSFET

Voltage

#### Current

70 A

#### Features

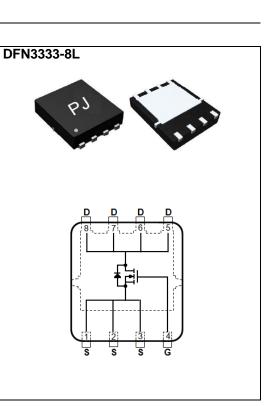
•  $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@10A<3.8m\Omega$ 

30 V

- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@5A<5.5m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.001 ounces, 0.03 grams



## **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	30	N	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C		70		
	$T_{\rm C}=100^{\circ}{\rm C}$		44	А	
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	280		
Power Dissipation	T <sub>C</sub> =25°C	D	39	14/	
	$T_{\rm C}=100^{\circ}{\rm C}$	PD -	15.6	W	
Continuous Drain Current	T <sub>A</sub> =25°C		16	٨	
	T <sub>A</sub> =70°C	I <sub>D</sub>	13	— A	
Power Dissipation	T <sub>A</sub> =25°C		2.0	14/	
Power Dissipation	T <sub>A</sub> =70°C	PD -	1.3	W	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ extsf{ heta}JC}$	3.21		
	Junction to	P	62.5	°C/W	
	Ambient ction Temperature	R <sub>θJA</sub>			

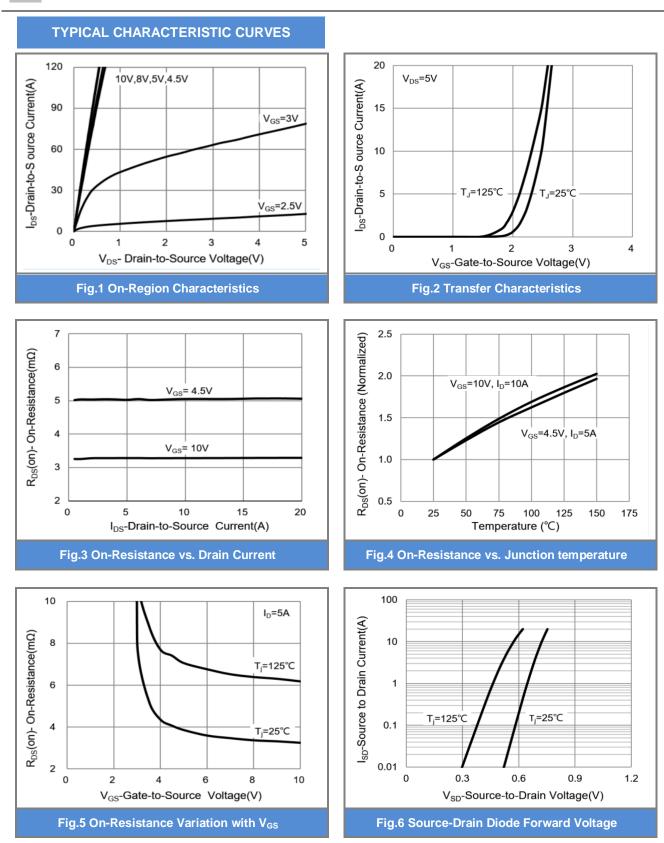


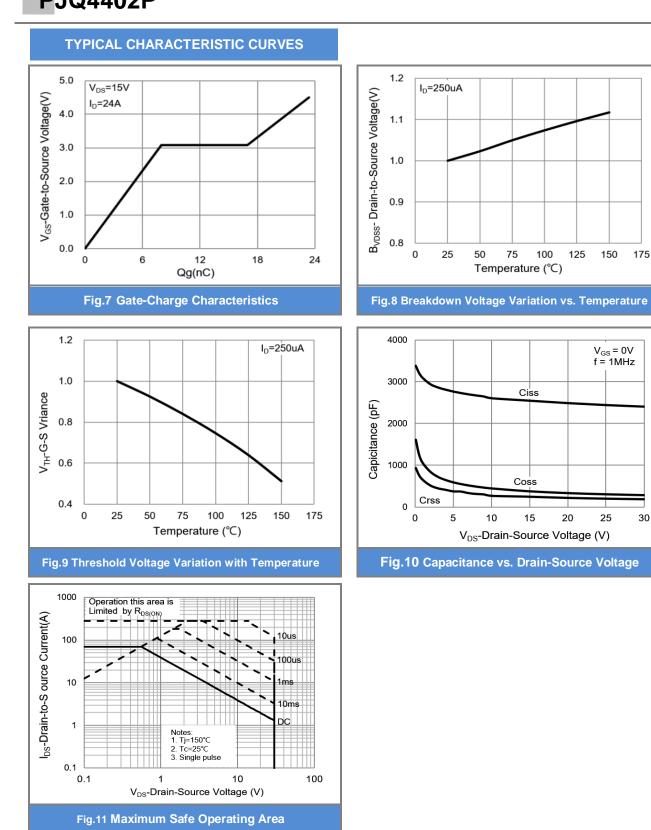
#### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static	OTMODE				III/AA.	onno
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1	1.6	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	3.3	3.8	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	5.0	5.5	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V <sub>DS</sub> =15V, I <sub>D</sub> =24A, V <sub>GS</sub> =4.5V <sup>(Note 2,3)</sup>	-	23	-	nC
Gate-Source Charge	$Q_{gs}$		-	8	-	
Gate-Drain Charge	$Q_gd$		-	9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	2436	-	pF
Output Capacitance	Coss		-	306	-	
Reverse Transfer Capacitance	Crss		-	196	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DS}$ =15V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V, R <sub>G</sub> =1Ω (Note 2,3)	-	32	-	ns
Turn-On Rise Time	tr		-	169	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	232	-	
Turn-Off Fall Time	t <sub>f</sub>		-	170	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	70	А
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.66	1.0	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150$  °C. Ratings are based on low frequency and duty cycles to keep initial  $T_J = 25$  °C.
- 4. The maximum current rating is package limited
- 5.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.

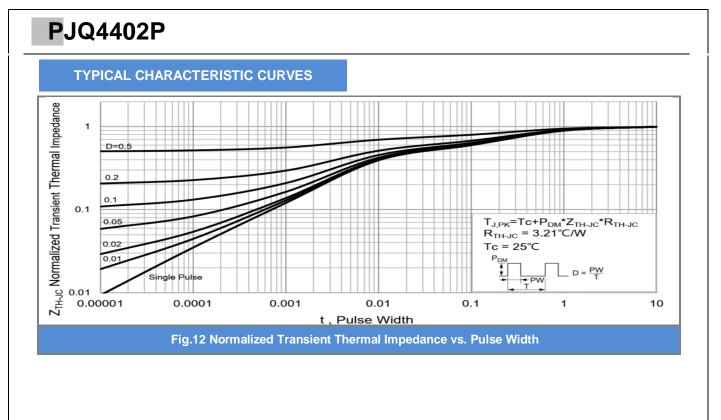








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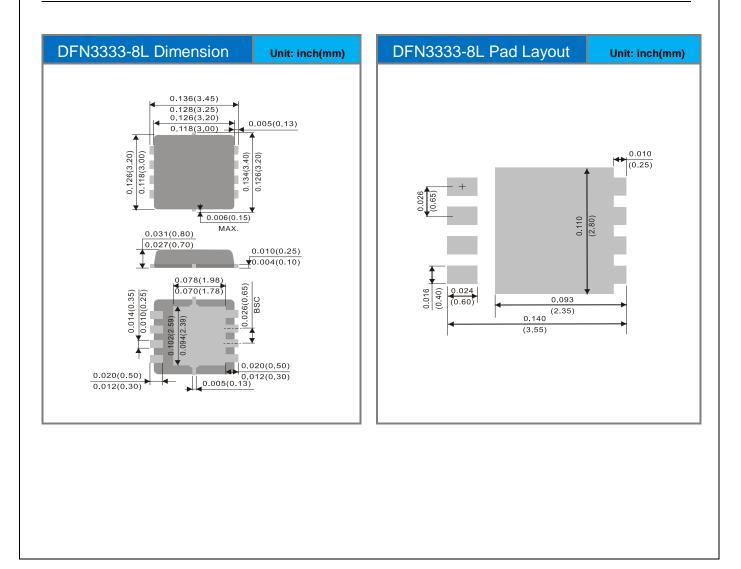




#### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ4402P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4402	Halogen free

#### **Packaging Information & Mounting Pad Layout**





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